# **Not Recommended for New Designs**

This product was manufactured for Maxim by an outside wafer foundry using a process that is no longer available. It is not recommended for new designs. The data sheet remains available for existing users.

A Maxim replacement or an industry second-source may be available. Please see the QuickView data sheet for this part or contact technical support for assistance.

For further information, contact Maxim's Applications Tech Support.



### **General Description**

Maxim's MXL1178 and MXL1179 are dual and quad micropower, precision op amps. They feature an extremely low 17µA max per op amp supply current, as well as precision offset specifications: 30µV offset voltage, and 50pA offset current. Both offset parameters have low drift over temperature and time.

The MXL1178 and MXL1179 can operate from a single supply (e.g., one lithium cell or two NiCd cells). The input voltage range includes ground. The output stage swings to within a few millivolts of ground while sinking current, which eliminates pull-down resistors and saves

Both devices are optimized for +5V single-supply operation, but specifications for ±15V operation are also provided.

Maxim's MXL1178 and MXL1179 are pin compatible with industry standards such as the LT1178 and LT1179. For applications that require smaller packaging, see the MAX478/MAX479 data sheet. For applications that require lower power, see the MAX406/MAX407/MAX409 1µA op amp data sheet.

## Applications

Battery- or Solar-Powered Systems: Portable Instrumentation Remote Sensor Amplifier Satellite Circuitry

Micropower Sample-and-Hold

Thermocouple Amplifier

Micropower Filters

Single Lithium Cell-Powered Systems

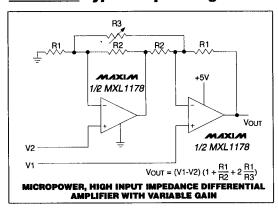
### **Features**

- ♦ 17µA Max Supply Current per Amplifier
- ♦ 70µV Max Offset Voltage
- ♦ 250pA Max Offset Current
- ♦ 5nA Max Input Bias Current
- ♦ 0.9μV<sub>p-p</sub> 0.1Hz to 10Hz Voltage Noise
- ♦ 1.5pA<sub>p-p</sub> 0.1Hz to 10Hz Current Noise
- ♦ 0.5μV/°C Offset-Voltage Drift
- ♦ 85kHz Gain-Bandwidth Product
- ♦ 0.04V/µs Siew Rate
- ♦ Single-Supply Operation: Input Voltage Range Includes Ground **Output Swings to Ground while Sinking Current** No Pull-Down Resistors Required
- ♦ Output Sources and Sinks 5mA Load Current

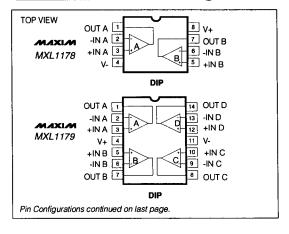
### **Ordering Information**

PART	TEMP. RANGE	PIN-PACKAGE
MXL1178ACN8	0°C to +70°C	8 Plastic DIP
MXL1178CN8	0°C to +70°C	8 Plastic DIP
MXL1178S	0°C to +70°C	16 Wide SO
MXL1178IN8	-40°C to +85°C	8 Plastic DIP
MXL1179ACN	0°C to +70°C	14 Plastic DIP
MXL1179CN	0°C to +70°C	14 Plastic DIP
MXL1179S	0°C to +70°C	16 Wide SO
MXL1179IN	-40°C to +85°C	14 Plastic DIP

#### **Typical Operating Circuit**



#### Pin Configurations



### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage	±22V
Differential Input Voltage	
Input VoltageEqual to Positive S	upply Voltage
5V Below Negative S	upply Voltage
Output Short-Circuit Duration	Continuous
Continuous Power Dissipation (TA = +70°C)	

8-Pin Plastic DIP (derate 9.09mW/°C above +70°C) ... 727mW 14-Pin Plastic DIP (derate 10.00mW/°C above +70°C) 800mW

 Operating Temperature Ranges:
 .0°C to +70°C

 MXL117\_AC\_\_/C\_\_/S
 .0°C to +85°C

 MXL117\_L
 .40°C to +85°C

 Storage Temperature Range
 .65°C to +150°C

 Lead Temperature (soldering, 10sec)
 +300°C

16-Pin Wide SO (derate 9.52mW/°C above +70°C)... 762mW

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

(Vs = 5V, 0V, VcM = 0.1V, Vo = 1.4V, TA =  $+25^{\circ}$ C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MXL1178AC MXL1179AC			MX	C/VS C/VS	UNITS	
			MIN	TYP	MAX	MIN	TYP	MAX	
		MXL1178		30	70		40	120	
Input Offset Voltage	Vos	MXL1179		35	100		40	150	μ٧
		MXL1178S_					80	450	
		MXL1179S					90_	600	
Long-Term Input Offset-Voltage Stability	$\frac{\Delta V_{OS}}{\Delta Time}$			0.5			0.6		μV/Mo
Input Offset Current	los			0.05	0.25		0.05	0.35	nΑ
Input Bias Current	I <sub>B</sub>			3	5		3	6	nΑ
Input Noise Voltage	en	0.1Hz to 10Hz (Note 1)		0.9	2.0		0.9		$\mu V_{p-p}$
		f <sub>O</sub> = 10Hz (Note 1)		50	75		50		n\/\/\\\\
Input Noise Voltage Density		f <sub>O</sub> = 1000Hz (Note 1)		49	65		49		nV/√Hz
Input Noise Current	in	0.1Hz to 10Hz (Note 1)		1.5	2.5		1.5		pA <sub>p-p</sub>
		f <sub>O</sub> = 10Hz (Note 1)		0.03	0.07		0.03		pA/√Hz
Input Noise Current Density		f <sub>O</sub> = 1000Hz		0.01			0.01		
Input Resistance	Rin	Differential mode (Note 1)	0.8	2.0		0.6	2.0		
		Common mode		12			12		GΩ
Input Voltage Range			3.5	3.9		3.5	3.9		v
			0	-0.3		0	-0.3		· ·
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = 0V to 3.5V	93	103		90	102		dB
Power-Supply Rejection Ratio	PSRR	V <sub>S</sub> = 2.2V to 12V	94	104		92	104		dB
Large-Signal	Λ -	V <sub>O</sub> = 0.03V to 4V, no load (Note 1)	140	700		110	700		V/mV
Voltage Gain	Avol	$V_{\rm O} = 0.03 \text{V to } 3.5 \text{V}, R_{\rm L} = 50 \text{k}\Omega$	80	200		70	200		
		Output low, no load		6.5	9.0		6.5	9.0	
		Output low, 2kΩ to GND		0.2	0.6		0.2	0.6	mV
Maximum Output Voltage Swing	V <sub>OUT</sub>	Output low, I <sub>SINK</sub> = 100µA		120	160		120	160	]
voltage enting		Output high, no load	4.2	4.4		4.2	4.4		.,
		Output high, 2kΩ to GND	3.5	3.8		3.5	3.8		- V
Slew Rate	SR	A <sub>V</sub> = +1, C <sub>L</sub> = 10pF (Note 1)	0:013	0.025		0.013	0.025		V/µs
Gain-Bandwidth Product	GBW	fo≤5kHz		60			60		kHz
		$V_S = 5V$ , 0V, $V_O = 1.4V$		13	18		14	21	
Supply Current per Amplifier	Is	$V_S = \pm 1.5V, V_O = 0V$		12	17		13	20	μΑ
Channel Separation		$\Delta V_{IN} = 3V$ , $R_L = 10k\Omega$	<u></u>	130			130		dB
Minimum Supply Voltage	Vs	(Note 2)		2.0	2.2		2.0	2.2	V

### **ELECTRICAL CHARACTERISTICS**

 $(V_S = 5V, 0V, V_{CM} = 0.1V, V_O = 1.4V, T_A = -40^{\circ}C$  to  $+85^{\circ}C$  for I grades,  $T_A = 0^{\circ}C$  to  $+70^{\circ}C$  for S grades, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MXL1178I MXL1179I			M: M:	-	UNITS	
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	Vos	MXL1178		80	315		120_	650	μV
input Offset voltage	VOS	MXL1179		80	345		130	800	μ <b>ν</b>
Input Offset-Voltage Drift	$\frac{\Delta V_{OS}}{\Delta T}$	(Note 1)		0.6	3.0		0.8	4.5	μV/°C
Input Offset Current	los			0.07	0.7		0.06	0.50	nA
Input Bias Current	IB			4	8		3	7	nA
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = 0.05V to 3.2V for I grade	84	98					dB
		V <sub>CM</sub> = 0V to 3.4V for S grade				86	100		4.5
Power-Supply	PSRR	V <sub>S</sub> = 3.0V to 12V for I grade	86	100					dB
Rejection Ratio	Fonn	V <sub>S</sub> = 2.5V to 12V for S grade				88	102		_ GB
Large-Signal	Avol	V <sub>O</sub> = 0.05V to 4V, no load (Note 1)	55	350		80	500		V/mV
Voltage Ğain	AVOL	$V_0 = 0.05V$ to 3.5V, $R_L = 50k\Omega$	35	130		45	160		*////
		Output low, no load		9	13		8	11	mV
Maximum Output	Vout	Output low, I <sub>SINK</sub> = 100µA		160	220		140	190	
Voltage Swing	,001	Output high, no load	3.9	4.2		4.1	4.3		v
		Output high, 2kΩ to GND	3.0	3.7		3.3	3.8		
Supply Current per Amplifier	Is			15	27		15	24	μА

#### **ELECTRICAL CHARACTERISTICS**

(VS = 5V, 0V, V<sub>CM</sub> = 0.1V, V<sub>O</sub> = 1.4V,  $T_A = 0$ °C to +70°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MXL1178AC MXL1179AC			MXL1178C MXL1179C			
			MIN	TYP	MAX	MIN	TYP	MAX		
Input Offset Voltage	Vos	MXL1178		50	170		65	250	μ∨	
input Onset voltage	VOS	MXL1179		60	200		70	290	μν	
Input Offset-Voltage Drift	$\frac{\Delta V_{OS}}{\Delta T}$	(Note 1)		0.5	2.2		0.6	3.0	μV/°C	
Input Offset Current	los			0.06	0.35		0.06	0.50	nA	
Input Bias Current	IB			3	6		3	7	nA	
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = 0V to 3.4V	90	101		86	100		dB	
Power-Supply Rejection Ratio	PSRR	V <sub>S</sub> = 2.5V to 12V	90	102		88	102		dB	
Large-Signal	Avol	V <sub>O</sub> = 0.05V to 4V, no load (Note 1)	105	500		80	500		V/mV	
Voltage Ğain		$V_O = 0.05V$ to 3.5V, $R_L = 50k\Omega$	55	160		45	160		7	
		Output low, no load		8	11		8	11	mV	
Maximum Output	V <sub>OUT</sub>	Output low, I <sub>SINK</sub> = 100μA		140	190		140	190	1 ""	
Voltage Swing	1001	Output high, no load	4.1	4.3		4.1	4.3		V	
		Output high, 2kΩ to GND	3.3	3.8		3.3	3.8			
Supply Current per Amplifier	Is			14	21		15	24	μА	

## **ELECTRICAL CHARACTERISTICS**

( $V_S = \pm 15V$ ,  $T_A = +25$ °C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MXL1178AC MXL1179AC			MXL1178C/VS MXL1179C/VS			
			MIN	TYP	MAX	MIN	TYP	MAX		
			i	80	350		100	480		
Input Offset Voltage	Vos	MXL1178S					150	900	μ۷	
		MXL1179S					160	1050	1	
Input Offset Current	los			0.05	0.25		0.05	0.35	nA	
Input Bias Current	l <sub>B</sub>			3	5		3	6	nA	
Input Voltage Range			13.5 -15.0	13.9 -15.3		13.5 -15.0	13.9 -15.3		٧	
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = +13.5V, -15V	97	106		94	106		dB	
Power-Supply Rejection Ratio	PSRR	$V_S = 5V$ , 0V to ±18V	96	112		94	112	*	dB	
Large-Signal	Avol	$V_O = \pm 10V$ , $R_L = 50k\Omega$	300	1200		250	1000		V/mV	
Voltage Ğain	AVOL	$V_O = \pm 10V$ , no load	600	2500		400	2500		] *////	
Maximum Output	V	$R_L = 50k\Omega$	±13.0	±14.2		±13.0	±14.2		v	
Voltage Swing	Vout	$R_L = 2k\Omega$	±11.0	±12.7		±11.0	±12.7		7 <b>'</b>	
Slew Rate	SR	$A_V = +1V$	0.02	0.04		0.02	0.04		V/µs	
Gain Bandwidth Product	GBW	f <sub>O</sub> ≤ 5kHz		85			85		kHz	
Supply Current per Amplifier	Is			16	21		17	25	μА	

### **ELECTRICAL CHARACTERISTICS**

(Vs =  $\pm 15$ V, TA = -40°C to +85°C for I grades, TA = 0°C to +70°C for S grades, unless otherwise noted.)

PARAMETER	SYMBOL CONDITIONS			MXL1178I MXL1179I			MXL1178S MXL1179S			
			MIN	TYP	MAX	MIN	TYP	MAX		
Input Offset Voltage	Vos	MXL1178		130	740		190	1150	μ∨	
input Onset voltage	VOS	MXL1179		130	740		200	1300	μν	
Input Offset-Voltage Drift	$\frac{\Delta V_{OS}}{\Delta T}$	(Note 1)		0.7	4.0		0.9	5.5	μV/°C	
Input Offset Current	los			0.07	0.7		0.06	0.35	nA	
Input Bias Current	IB			4	8		3	7	nA	
Large-Signal Voltage Gain	Avol	$V_O = \pm 10V$ , $R_L = 50k\Omega$	100	500		150	750		V/mV	
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = +13V, -14.9V	88	103		91	104		dB	
Power-Supply Rejection Ratio	PSRR	V <sub>S</sub> = 5V, 0V to ±18V	88	109		91	110		dB	
Maximum Output Voltage Swing	V <sub>OUT</sub>	$R_L = 5k\Omega$	±11.0	±13.5		±11.0	±13.5		V	
Supply Current per Amplifier	Is			19	30		18	28	μА	

#### **ELECTRICAL CHARACTERISTICS**

(Vs =  $\pm 15$ V, T<sub>A</sub> = 0°C to +70°C, unless otherwise noted.)

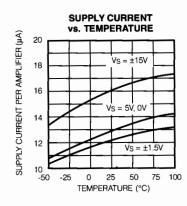
PARAMETER	SYMBOL	CONDITIONS		(L1178 (L1179		M: M:	UNITS		
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	Vos			100	480		130	660	μV
Input Offset-Voltage Drift	$\frac{\Delta V_{OS}}{\Delta T}$	(Note 1)		0.6	2.8		0.7	4.0	μV/°C
Input Offset Current	los			0.06	0.35		0.06	0.35	nA
Input Bias Current	IB	,		3	6		3	7	nA
Large-Signal Voltage Gain	A <sub>VOL</sub>	$V_O = \pm 10V$ , $R_L = 50k\Omega$	200	800		150	750		V/mV
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = +13V, -15V	94	104		91	104		dB
Power-Supply Rejection Ratio	PSRR	V <sub>S</sub> = 5V, 0V to ±18V	93	110		91	110		dB
Maximum Output Voltage Swing	Vout	$R_L = 5k\Omega$	±11.0	±13.6		±11.0	±13.6		V
Supply Current per Amplifier	Is			17	24		18	28	μА

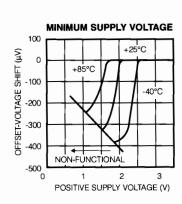
Note 1: Guaranteed by design.

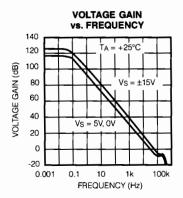
Note 2: Power-supply rejection ratio is measured at the minimum supply voltage. The op amps actually work at 1.7V supply, but with additional input offset-voltage skew.

Note 3: During testing at -40°C, the 5V power-supply turn-on time is less than 0.5sec.

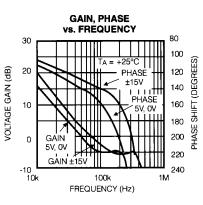
## **Typical Operating Characteristics**

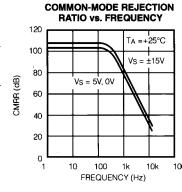


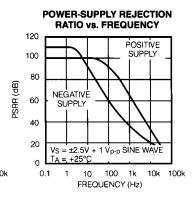


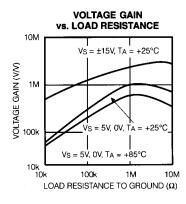


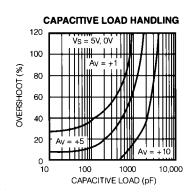
### Typical Operating Characteristics (continued)

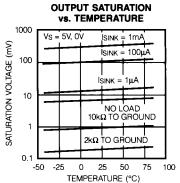




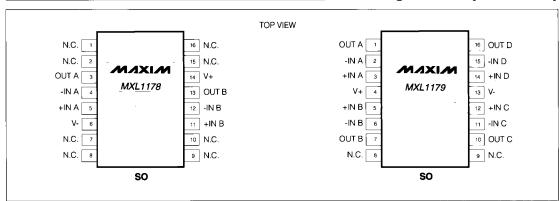




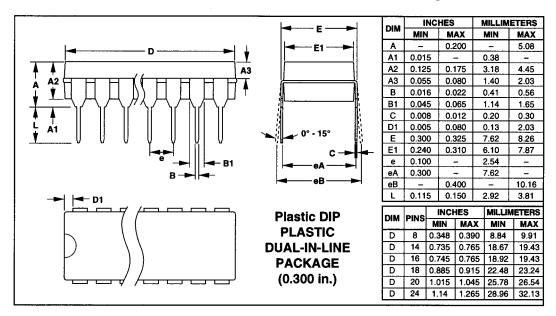




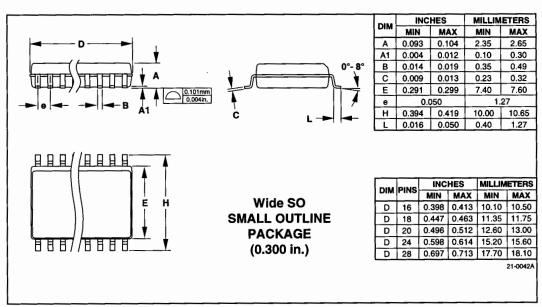
### Pin Configurations (continued)



### Package Information



## Package Information (continued)



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